

L Number	Hits	Search Text	DB	Time stamp
1	2	"20040042298"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 14:38
2	42946	phase adj change\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 15:06
3	783957	memory and device	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 15:07
4	2870	BJT	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 15:07
5	580685	transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 15:07
6	1049	(phase adj change\$5) and (memory and device) and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 15:09
7	36561	active adj region	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 15:09
8	55	((phase adj change\$5) and (memory and device) and transistor) and (active adj region)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 15:11
9	54171	348/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 15:12
10	51	((((phase adj change\$5) and (memory and device) and transistor) and (active adj region))) and (not 348/\$.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 16:30
11	1196	chalcogenide and memory	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 16:31
12	275725	257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 16:31

13	151434	438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 16:32
14	231	((phase adj change\$5) and (memory and device) and transistor) and 257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 18:06
15	80	connecting adj active adj region	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 18:51
16	5	"6440837"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 18:52
17	10	"6423621"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 18:53
19	0	((connecting adj active adj region) and memory) and EPROM	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 18:53
18	42	(connecting adj active adj region) and memory	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/21 18:54